PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Satoshi TAKEI et al.

Application No.: 10/565,968

Filed: January 31, 2006 Docket No.: 126821

For: UNDERLAYER COATING FORMING COMPOSITION FOR LITHOGRAPHY CONTAINING COMPOUND HAVING PROTECTED CARBOXYL GROUP

<u>INFORMATION DISCLOSURE STATEMENT</u>

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- 2. Relevance of one or more non-English language reference is discussed in the specification. See References <u>1-8</u>.
- 3. One or more reference cited herein was cited in the International Search Report. An English language version of the International Search Report is attached for the Examiner's information. See References 9-13.
- 4. In accordance with 37 CFR §1.98(a)(2)(ii), copies of any U.S. patents and patent application publications are not attached.
- 5. An English language Abstract of one or more non-English language reference is attached hereto. See References 1-13.

- 6. A computer-generated English language translation of one or more Japanese Patent Publication cited herein has been obtained from the website of the Japanese Patent Office ([http://www.jpo.go.jp]), and is attached, but has not been reviewed for accuracy. See References 1-3, and 5-13.
- References 20-23 correspond to references 9 and 11-13, respectively.

Respectfully submitted,

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Date: May 15, 2006

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INFORMATION DISCLOSURE STATEMENT								
(Use several sheets if necessary)				APPLICANT(S) Satoshi TAKEl et al.				
				FILING DATE January 31, 2006		GROUP		
- 1		FORE	IGN PATI	ENT DOC	UMENTS			
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(Use several sheets if necessary)				APPLICANT(S) Satoshi TAKEI et al.				
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